NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE80H16 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

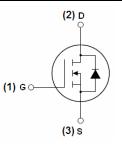
- V_{DS} =80V, I_{D} =160A $R_{DS(ON)}$ <4.7m Ω @ V_{GS} =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Automotive applications
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE80H16	NCE80H16	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	80	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	160	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	113	А
Pulsed Drain Current	I _{DM}	500	А
Maximum Power Dissipation	P _D	285	W
Derating factor		1.9	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	1936	mJ



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NCE80H16

Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$	

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	R _{θJC}	0.53	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	80	88	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	3.7	4.7	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	60	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}	\/ -05\/\/ -0\/	-	6500	-	PF
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	-	810	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIΠZ	-	310	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	31.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =40V, I_D =2A, R_L =15 Ω	-	33	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =10V, R_{G} =2.5 Ω	-	46	-	nS
Turn-Off Fall Time	t _f		-	17.5	-	nS
Total Gate Charge	Q_g	1/ 40\/ 00 4	-	130		nC
Gate-Source Charge	harge V_{DS} =40V, I_D =20A,		-	36		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	46		nC
Drain-Source Diode Characteristics	1					
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =40A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	160	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	51	-	nS
Reverse Recovery Charge	Qrr	di/dt = 500A/µs ^(Note3)	-	61	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

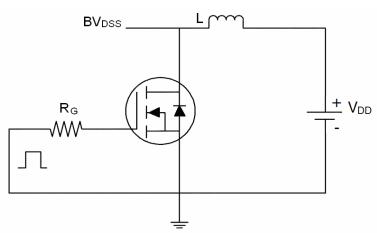
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}\text{C}\,\text{,V}_\text{DD}\text{=}40\text{V}\text{,V}_\text{G}\text{=}10\text{V}\text{,L=}0.5\text{mH}\text{,Rg=}25\Omega$

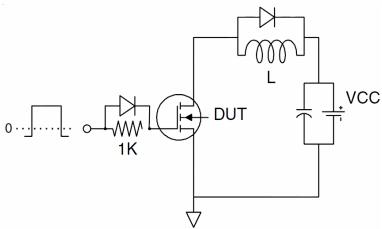


Test circuit

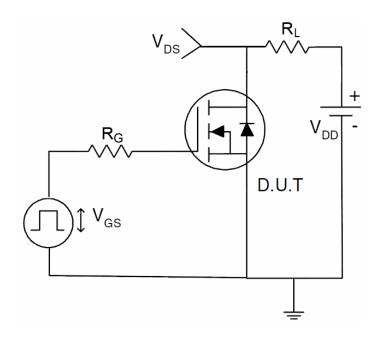
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

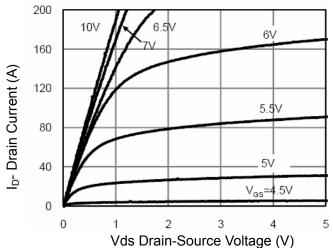


Figure 1 Output Characteristics

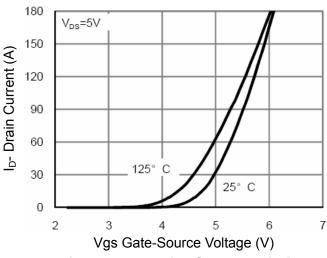


Figure 2 Transfer Characteristics

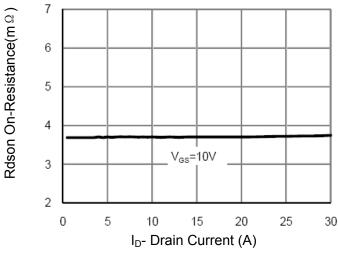


Figure 3 Rdson- Drain Current

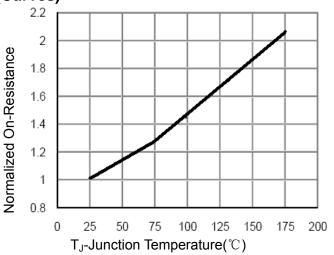


Figure 4 Rdson-JunctionTemperature

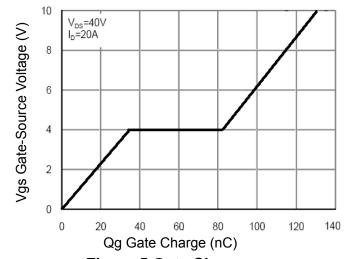


Figure 5 Gate Charge

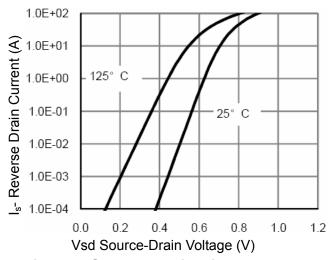


Figure 6 Source- Drain Diode Forward



NCE80H16

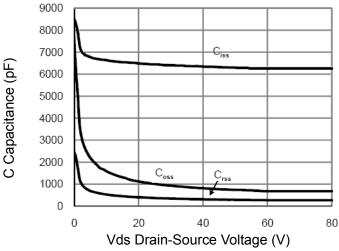


Figure 7 Capacitance vs Vds

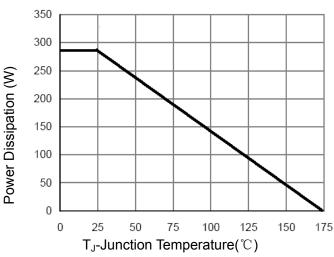


Figure 9 Power De-rating

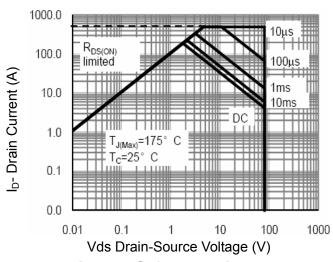


Figure 8 Safe Operation Area

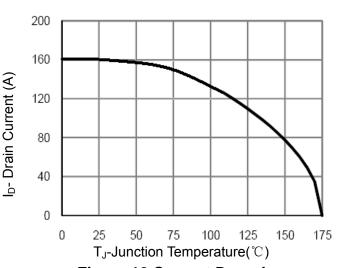


Figure 10 Current De-rating

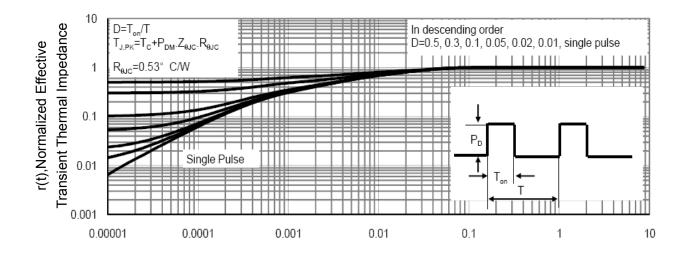
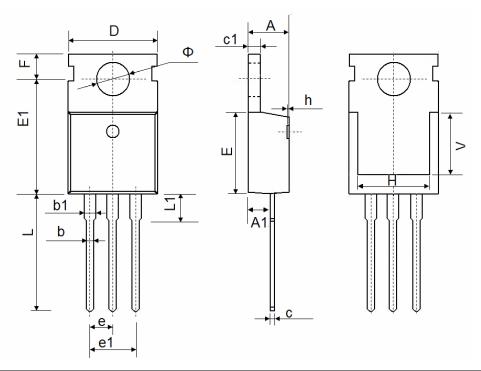


Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)



TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
Α	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.54	0 TYP.	0.100 TYP.			
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	V 7.500 REF.		0.295 REF.			
Ф	3.400	3.800	0.134	0.150		



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